
HD74LV574A

Octal Edge-Triggered D-type Flip-Flops with 3-state Outputs

HITACHI

ADE-205-280 (Z)
1st Edition
April 1999

Description

The HD74LV574A has eight edge-triggered D-type flip-flops with three-state outputs in a 20-pin package. Data at the D inputs meeting set up requirements, are transferred to the Q outputs on positive going transitions of the clock input. When the clock input goes low, data at the D inputs will be retained at the outputs until clock input returns high again. When a high logic level is applied to the output control input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0\text{ V}$ to 5.5 V operation
- All inputs $V_{IH}(\text{Max.}) = 5.5\text{ V}$ ($@V_{CC} = 0\text{ V}$ to 5.5 V)
- All outputs $V_O(\text{Max.}) = 5.5\text{ V}$ ($@V_{CC} = 0\text{ V}$)
- Typical V_{OL} ground bounce $< 0.8\text{ V}$ ($@V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- Typical V_{OH} undershoot $> 2.3\text{ V}$ ($@V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- Output current $\pm 8\text{ mA}$ ($@V_{CC} = 3.0\text{ V}$ to 3.6 V), $\pm 16\text{ mA}$ ($@V_{CC} = 4.5\text{ V}$ to 5.5 V)

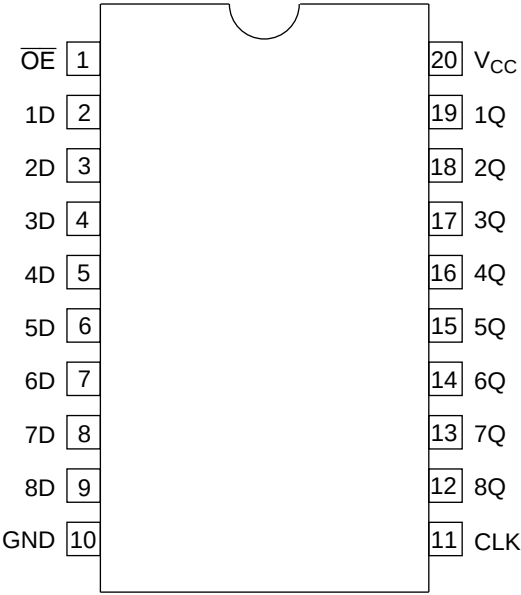
HD74LV574A

Function Table

Inputs			
OE	CLK	D	Output Q
L	↑	H	H
L	↑	L	L
L	↓	X	Q ₀
H	X	X	Z

Note: H: High level
L: Low level
X: Immaterial
Z: High impedance
↑: Low to high transition
↓: High to low transition
Q₀: Output level before the indicated steady state input conditions were established

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{CC}	−0.5 to 7.0	V	
Input voltage range* ¹	V _I	−0.5 to 7.0	V	
Output voltage range* ^{1, 2}	V _O	−0.5 to V _{CC} + 0.5 −0.5 to 7.0	V	Output: H or L V _{CC} : Z or V _{CC} : OFF
Input clamp current	I _{IK}	−20	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	V _O < 0 or V _O > V _{CC}
Continuous output current	I _O	±35	mA	V _O = 0 to V _{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±70	mA	
Maximum power dissipation at Ta = 25°C (in still air)* ³	P _T	835 757	mW	SOP TSSOP
Storage temperature	Tstg	−65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

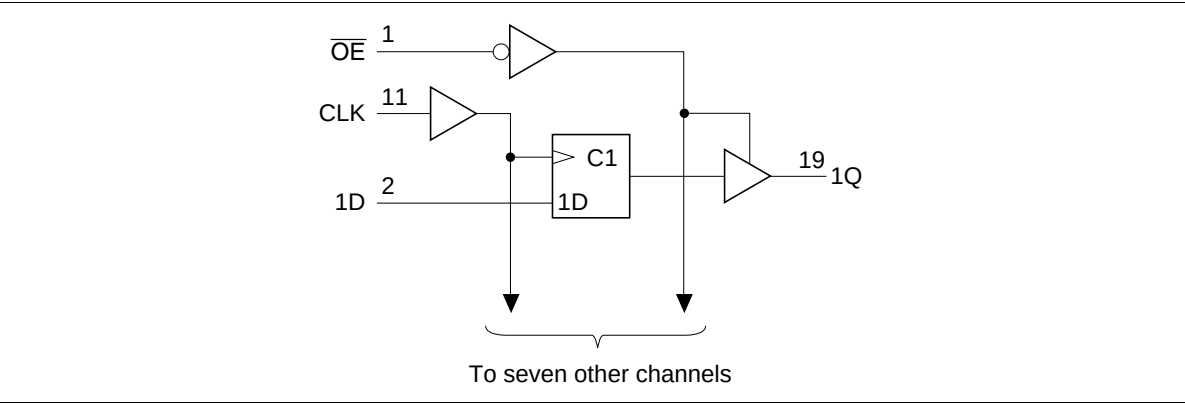
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	2.0	5.5	V	
Input voltage range	V_I	0	5.5	V	
Output voltage range	V_O	0	V_{CC}	V	H or L
		0	5.5		Output: Z
Output current	I_{OH}	—	−50	μA	$V_{CC} = 2.0\text{ V}$
		—	−2	mA	$V_{CC} = 2.3\text{ to }2.7\text{ V}$
		—	−8		$V_{CC} = 3.0\text{ to }3.6\text{ V}$
		—	−16		$V_{CC} = 4.5\text{ to }5.5\text{ V}$
	I_{OL}	—	50	μA	$V_{CC} = 2.0\text{ V}$
		—	2	mA	$V_{CC} = 2.3\text{ to }2.7\text{ V}$
		—	8		$V_{CC} = 3.0\text{ to }3.6\text{ V}$
		—	16		$V_{CC} = 4.5\text{ to }5.5\text{ V}$
Input transition rise or fall rate	$\Delta t/\Delta v$	0	200	ns/V	$V_{CC} = 2.3\text{ to }2.7\text{ V}$
		0	100		$V_{CC} = 3.0\text{ to }3.6\text{ V}$
		0	20		$V_{CC} = 4.5\text{ to }5.5\text{ V}$
Operating free-air temperature	T_a	−40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

- $T_a = -40$ to 85°C

Item	Symbol	V_{CC} (V)*	Min	Typ	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.0	1.5	—	—	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	—	—		
		3.0 to 3.6	$V_{CC} \times 0.7$	—	—		
		4.5 to 5.5	$V_{CC} \times 0.7$	—	—		
	V_{IL}	2.0	—	—	0.5		
		2.3 to 2.7	—	—	$V_{CC} \times 0.3$		
		3.0 to 3.6	—	—	$V_{CC} \times 0.3$		
		4.5 to 5.5	—	—	$V_{CC} \times 0.3$		
Output voltage	V_{OH}	Min to Max	$V_{CC} - 0.1$	—	—	V	$I_{OH} = -50\ \mu\text{A}$
		2.3	2.0	—	—		$I_{OH} = -2\ \text{mA}$
		3.0	2.48	—	—		$I_{OH} = -8\ \text{mA}$
		4.5	3.8	—	—		$I_{OH} = -16\ \text{mA}$
	V_{OL}	Min to Max	—	—	0.1		$I_{OL} = 50\ \mu\text{A}$
		2.3	—	—	0.4		$I_{OL} = 2\ \text{mA}$
		3.0	—	—	0.44		$I_{OL} = 8\ \text{mA}$
		4.5	—	—	0.55		$I_{OL} = 16\ \text{mA}$
Input current	I_{IN}	0 to 5.5	—	—	± 1	μA	$V_I = 5.5\ \text{V}$ or GND
Off-state output current	I_{OZ}	5.5	—	—	± 5	μA	$V_O = V_{CC}$ or GND
Quiescent supply current	I_{CC}	5.5	—	—	20	μA	$V_I = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I_{OFF}	0	—	—	5	μA	V_I or $V_O = 0\ \text{V}$ to $5.5\ \text{V}$
Input capacitance	C_{IN}	3.3	—	1.8	—	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

- $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = −40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Maximum clock frequency	fmax	60	100	—	50	—	MHz	C _L = 15 pF		
		50	85	—	40	—		C _L = 50 pF		
Propa- gation delay time	t _{PLH}	—	9.6	16.6	1.0	20.0	ns	C _L = 15 pF	CLK	Q
	t _{PHL}	—	11.6	19.6	1.0	23.0		C _L = 50 pF		
Enable time	t _{ZH}	—	9.2	16.1	1.0	19.0	ns	C _L = 15 pF	$\overline{OE}$	Q
	t _{ZL}	—	10.9	19.0	1.0	22.0		C _L = 50 pF		
Disable time	t _{HZ}	—	6.5	12.8	1.0	15.0	ns	C _L = 15 pF	$\overline{OE}$	Q
	t _{LZ}	—	8.4	17.5	1.0	20.0		C _L = 50 pF		
Setup time	t _{su}	5.5	—	—	5.5	—	ns		Data before CLK ↑	
Hold time	t _h	2.0	—	—	2.0	—	ns		Data after CLK ↑	
Pulse width	t _w	7.0	—	—	7.0	—	ns		CLK: H or L	

Switching Characteristics (cont)

- $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	Ta = 25°C			Ta = −40 to 85°C		Unit	Test Conditions	FROM (Input)	TO (Output)
		Min	Typ	Max	Min	Max				
Maximum clock frequency	fmax	80	145	—	65	—	MHz	C _L = 15 pF		
		55	120	—	45	—		C _L = 50 pF		
Propa- gation delay time	t _{PLH}	—	6.8	13.2	1.0	15.5	ns	C _L = 15 pF	CLK	Q
	t _{PHL}	—	8.1	16.7	1.0	19.0		C _L = 50 pF		
Enable time	t _{ZH}	—	6.4	12.8	1.0	15.0	ns	C _L = 15 pF	$\overline{OE}$	Q
	t _{ZL}	—	7.7	16.3	1.0	18.5		C _L = 50 pF		
Disable time	t _{HZ}	—	4.8	13.0	1.0	15.0	ns	C _L = 15 pF	$\overline{OE}$	Q
	t _{LZ}	—	6.1	15.0	1.0	17.0		C _L = 50 pF		
Setup time	t _{su}	3.5	—	—	3.5	—	ns		Data before CLK ↑	
Hold time	t _h	1.5	—	—	1.5	—	ns		Data after CLK ↑	
Pulse width	t _w	5.0	—	—	5.0	—	ns		CLK: H or L	

Switching Characteristics (cont)

- $V_{CC} = 5.0 \pm 0.5 \text{ V}$

		Ta = 25°C			Ta = −40 to 85°C				FROM	TO
Item	Symbol	Min	Typ	Max	Min	Max	Unit	Test Conditions	(Input)	(Output)
Maximum clock frequency	fmax	130	205	—	110	—	MHz	C _L = 15 pF		
		85	175	—	75	—		C _L = 50 pF		
Propa- gation delay time	t _{PLH}	—	4.8	8.6	1.0	10.0	ns	C _L = 15 pF	CLK	Q
	t _{PHL}	—	5.7	10.6	1.0	12.0		C _L = 50 pF		
Enable time	t _{ZH}	—	4.6	9.0	1.0	10.5	ns	C _L = 15 pF	$\overline{OE}$	Q
	t _{ZL}	—	5.5	11.0	1.0	12.5		C _L = 50 pF		
Disable time	t _{HZ}	—	3.5	9.0	1.0	10.5	ns	C _L = 15 pF	$\overline{OE}$	Q
	t _{LZ}	—	4.1	10.1	1.0	11.5		C _L = 50 pF		
Setup time	t _{su}	3.5	—	—	3.5	—	ns	Data before CLK ↑		
Hold time	t _h	1.5	—	—	1.5	—	ns	Data after CLK ↑		
Pulse width	t _w	5.0	—	—	5.0	—	ns	CLK: H or L		

Output-skew Characteristics

Item	Symbol	$V_{CC} \text{ (V)}$	Ta = 25°C			Ta = −40 to 85°C		Unit
			Min	Typ	Max	Min	Max	
Output skew	$t_{sk(O)}$	2.3 to 2.7	—	—	2.0	—	2.0	ns
		3.0 to 3.6	—	—	1.5	—	1.5	
		4.5 to 5.5	—	—	1.0	—	1.0	

Note: Skew between any outputs of the same package switching in the same direction. This parameter is warranted but not production tested.

Operating Characteristics

- $C_L = 50\text{ pF}$

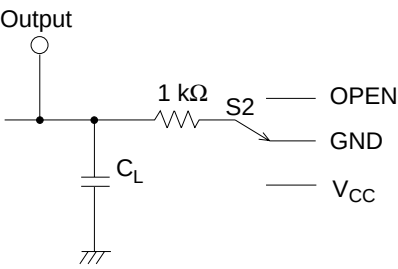
Item	Symbol	$V_{CC}\text{ (V)}$	$T_a = 25^\circ\text{C}$			Unit	Test Conditions
			Min	Typ	Max		
Power dissipation capacitance	C_{PD}	3.3	—	20.4	—	pF	$f = 10\text{ MHz}$
		5.0	—	23.8	—		

Noise Characteristics

- $C_L = 50\text{ pF}$

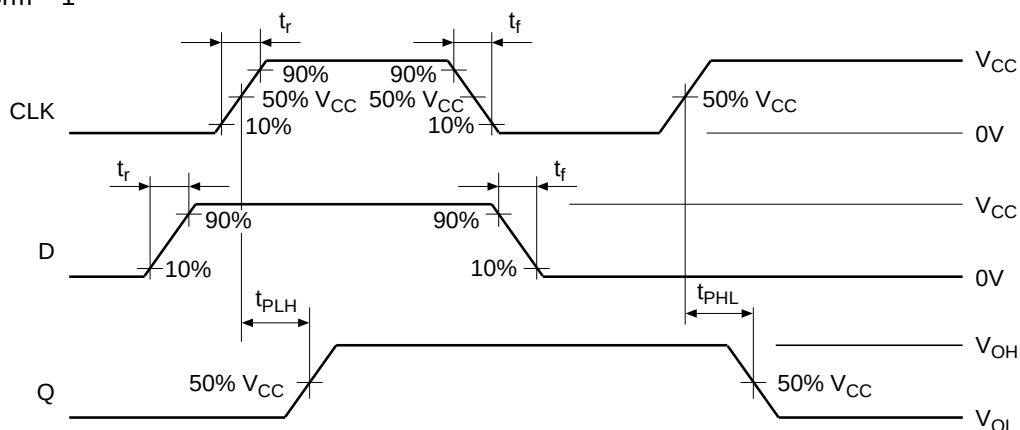
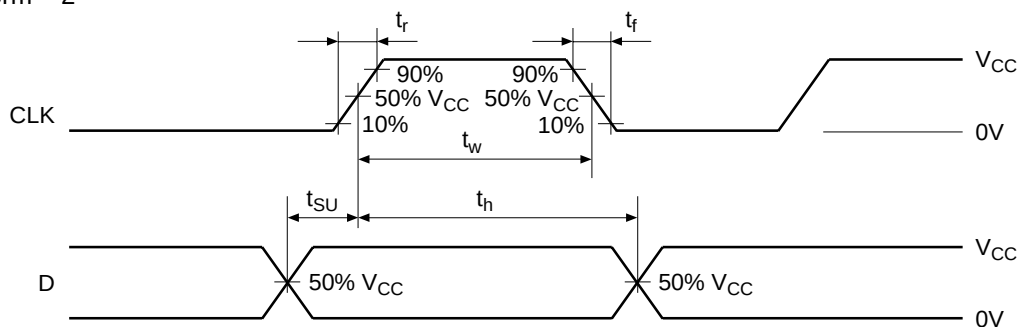
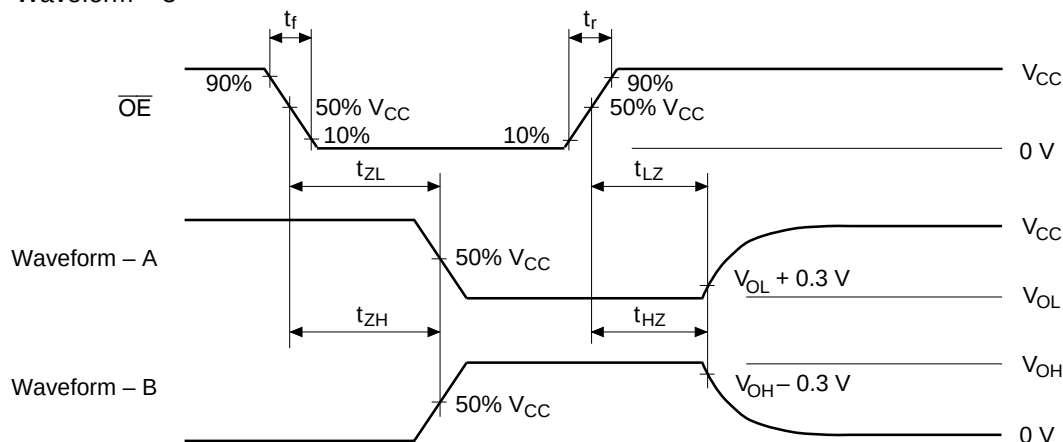
Item	Symbol	$V_{CC}\text{ (V)}$	$T_a = 25^\circ\text{C}$			Unit	Test Conditions
			Min	Typ	Max		
Quiet output, maximum dynamic V_{OL}	$V_{OL(P)}$	3.3	—	0.7	0.8	V	
Quiet output, minimum dynamic V_{OL}	$V_{OL(V)}$	3.3	—	−0.6	−0.8		
Quiet output, minimum dynamic V_{OH}	$V_{OH(V)}$	3.3	—	2.8	—		
High-level dynamic input voltage	$V_{IH(D)}$	3.3	2.31	—	—	V	
Low-level dynamic input voltage	$V_{IL(D)}$	3.3	—	—	0.99		

Test Circuit



TEST	S2
t_{PLH}/t_{PHL}	OPEN
t_{ZH}/t_{HZ}	GND
t_{ZL}/t_{LZ}	V_{CC}

Note: C_L includes the probe and jig capacitance.

• Waveform – 1

• Waveform – 2

• Waveform – 3


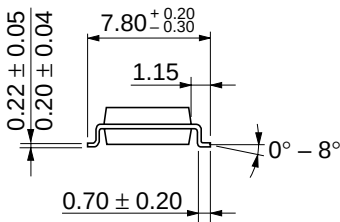
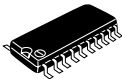
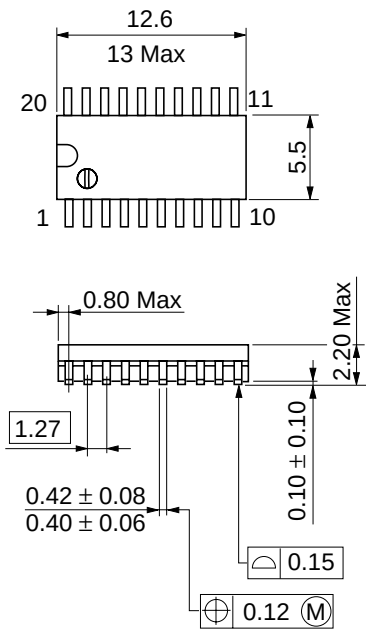
Notes: 1. Input waveform: $PRR \leq 1 \text{ MHz}$, $Z_o = 50 \Omega$, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$

2. Waveform-A is for an output with internal conditions such that the output is low except when disabled by the output control.

3. Waveform-B is for an output with internal conditions such that the output is high except when disabled by the output control.

4. The output is measured one at a time with one transition per measurement.

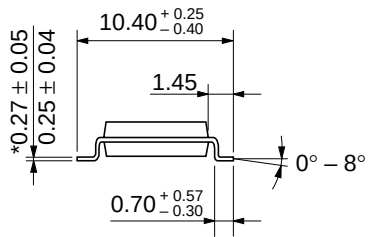
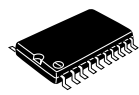
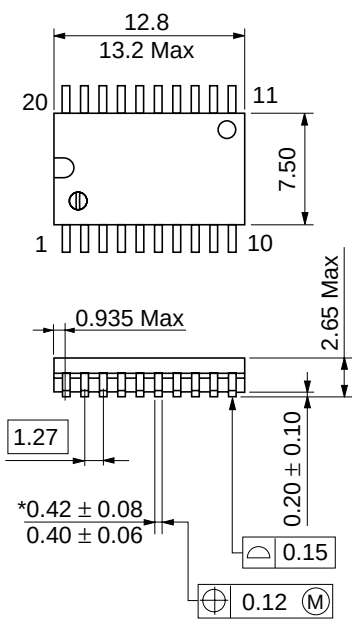
Package Dimensions



Dimension including the plating thickness
Base material dimension

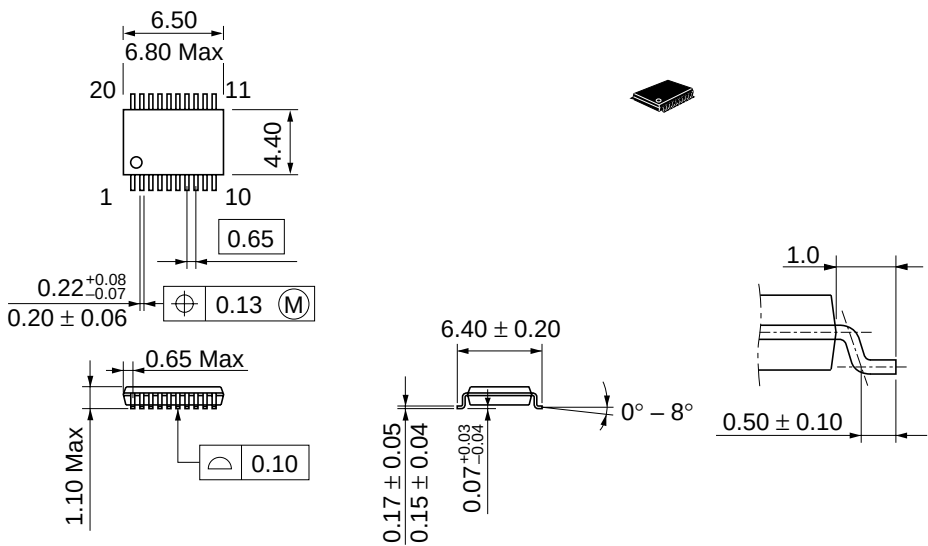
Hitachi Code	FP-20DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.31 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	—
Weight (reference value)	0.52 g



Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-20DA
JEDEC	—
EIAJ	—
Weight (reference value)	0.07 g

Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL	NorthAmerica	:	http://semiconductor.hitachi.com/
	Europe	:	http://www.hitachi-eu.com/hel/ecg
	Asia (Singapore)	:	http://www.has.hitachi.com.sg/grp3/sicd/index.htm
	Asia (Taiwan)	:	http://www.hitachi.com.tw/E/Product/SICD_Frame.htm
	Asia (HongKong)	:	http://www.hitachi.com.hk/eng/bo/grp3/index.htm
	Japan	:	http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1> (408) 433-0223	Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322
--	---

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533 Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180
--

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower, World Finance Centre,
Harbour City, Canton Road, Tsim Sha Tsui,
Kowloon, Hong Kong
Tel: <852> (2) 735 9218
Fax: <852> (2) 730 0281
Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.